

Features

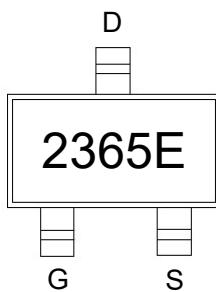
- Leading trench technology for low $R_{DS(on)}$
- Low Gate Charge

Product Summary

| V_{DS} | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| -20V | 33mΩ@-4.5V | -5.9A |
| | 55mΩ@-2.5V | |

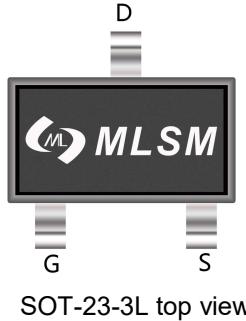
Application

- Video monitor
- Power management

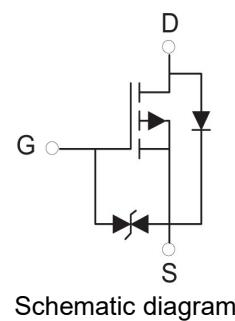


2365E: Device code

Marking and pin assignment



SOT-23-3L top view



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--|----------------------------------|-----------------|------|
| Common Ratings (TC=25°C Unless Otherwise Noted) | | | |
| V_{DS} | Drain-Source Breakdown Voltage | -20 | V |
| V_{GS} | Gate-Source Voltage | ±10 | V |
| T_J | Maximum Junction Temperature | 150 | °C |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |
| I_S | Diode Continuous Forward Current | Tc=25°C -5.9 | A |

Mounted on Large Heat Sink

| | | | | |
|-----------|--|---------|------|------|
| I_{DM} | Pulse Drain Current Tested | Tc=25°C | -23 | A |
| I_D | Continuous Drain Current | Tc=25°C | -5.9 | A |
| P_D | Maximum Power Dissipation | Tc=25°C | 1.8 | W |
| $R_{θJA}$ | Thermal Resistance Junction-to-Ambient | | 90 | °C/W |

Ordering Information (Example)

| Type | Package | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|-----------|---------|----------------------|-------------------------|----------------------------|---------------|
| MLSK2365E | SOT-23-3L | 2365E | 3,000 | 45,000 | 180,000 | 7" reel |

Electrical Characteristics (T_J=25°C unless otherwise noted)

| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
|---|----------------------------------|---|------|------|------|------|
| Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated) | | | | | | |
| BV _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =-250μA | -20 | - | - | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =-20V, V _{GS} =0V | -- | -- | -1 | μA |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} =±10V, V _{DS} =0V | -- | -- | ±10 | μA |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =-250μA | -0.4 | -0.8 | -1.0 | V |
| R _{DS(on)} | Drain-Source On-State Resistance | V _{GS} =-4.5V, I _D =-4A | -- | 26 | 33 | mΩ |
| | | V _{GS} =-2.5V, I _D =-4A | -- | 40 | 55 | mΩ |
| | | V _{GS} =-1.8V, I _D =-2A | -- | 70 | 120 | mΩ |

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

| | | | | | | |
|------------------|------------------------------|--|----|-----|----|----|
| C _{ISS} | Input Capacitance | V _{DS} =-10V, V _{GS} =0V, f=1MHz | -- | 540 | -- | pF |
| C _{OSS} | Output Capacitance | | -- | 120 | -- | pF |
| C _{RSS} | Reverse Transfer Capacitance | | -- | 100 | -- | pF |

Switching Characteristics

| | | | | | | |
|---------------------|---------------------|---|----|-----|----|----|
| Q _g | Total Gate Charge | V _{DS} =-10V, I _D =-5A, V _{GS} =-4.5V | -- | 13 | -- | nC |
| Q _{gs} | Gate Source Charge | | -- | 1.9 | -- | nC |
| Q _{gd} | Gate Drain Charge | | -- | 2 | -- | nC |
| t _{d(on)} | Turn-on Delay Time | V _{DS} =-10V, R _L =2.5Ω, V _{GS} =-10V, R _G =2.2Ω | -- | 5 | -- | nS |
| t _r | Turn-on Rise Time | | -- | 47 | -- | nS |
| t _{d(off)} | Turn-Off Delay Time | | -- | 52 | -- | nS |
| t _f | Turn-Off Fall Time | | -- | 69 | -- | nS |

Source-Drain Diode Characteristics

| | | | | | | |
|-----------------|--------------------|---|----|----|------|---|
| V _{SD} | Forward on voltage | T _j =25°C, I _S =-4A | -- | -- | -1.2 | V |
|-----------------|--------------------|---|----|----|------|---|

Typical Operating Characteristics

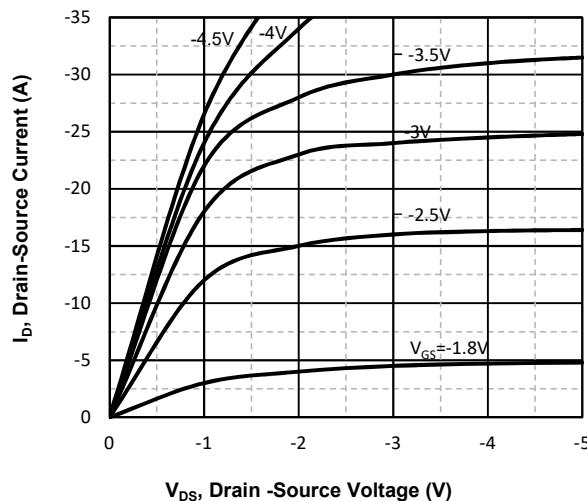


Fig1. Typical Output Characteristics

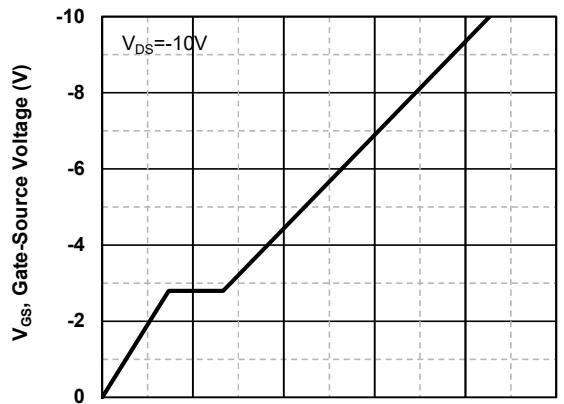


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

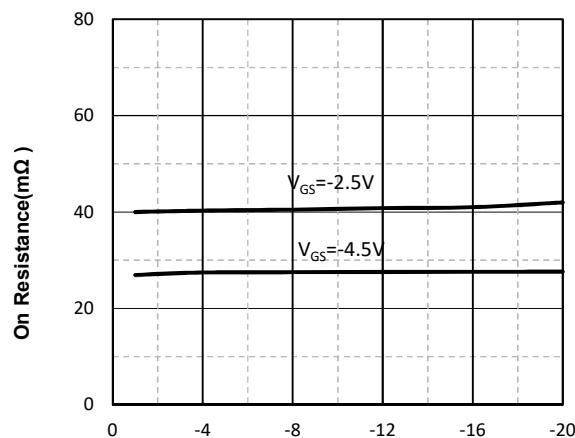


Fig3. Drain-Source on Resistance

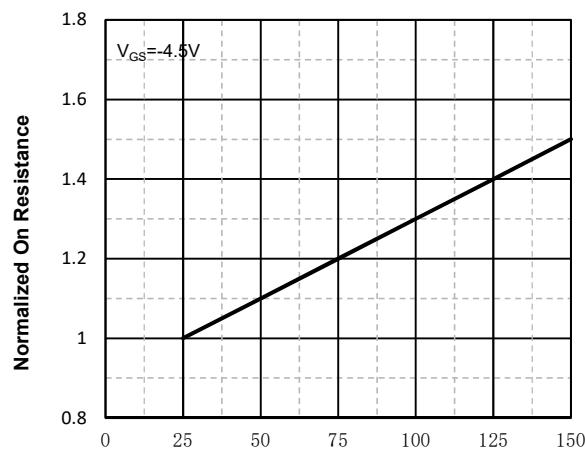


Fig4. Normalized On-Resistance Vs. Temperature

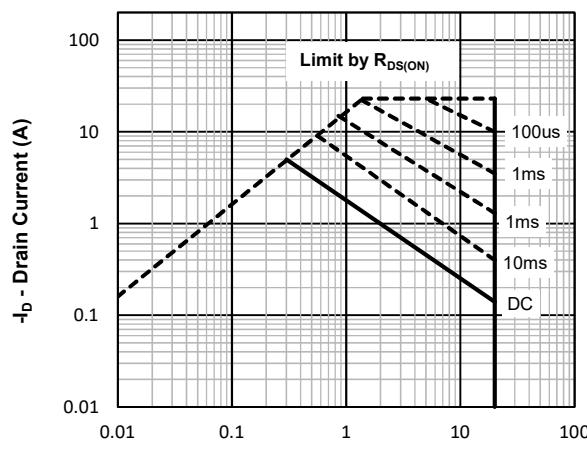


Fig5. Maximum Safe Operating Area

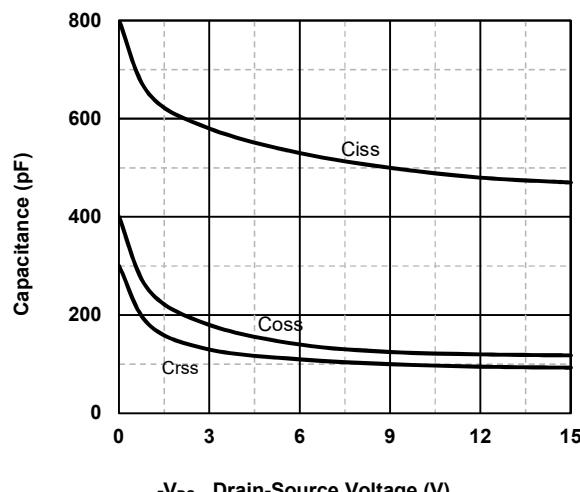
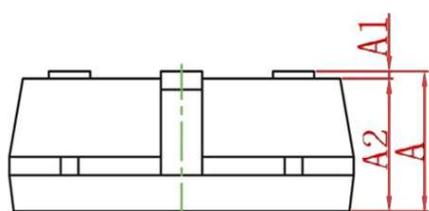
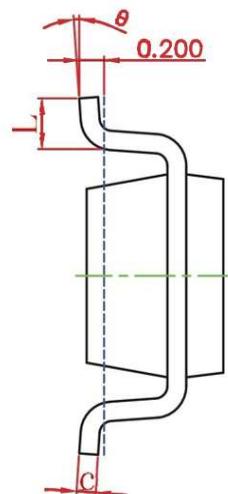
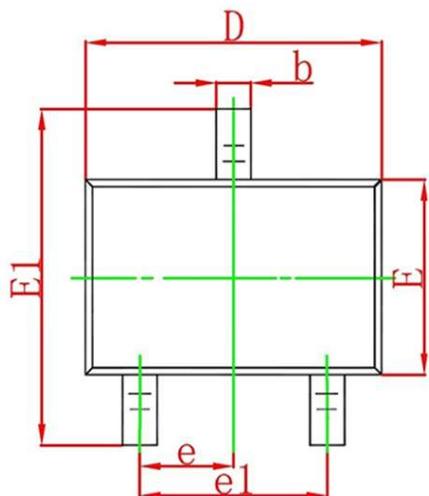


Fig6. Typical Capacitance Vs. Drain-Source Voltage

SOT-23-3L Package information


| Symbol | Dimensions in Millimeters(mm) | | Dimensions In Inches | |
|----------|-------------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.042 | 0.050 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.042 | 0.046 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.112 | 0.120 |
| E | 1.500 | 1.700 | 0.060 | 0.068 |
| E1 | 2.650 | 2.950 | 0.106 | 0.118 |
| e | 0.950TYP | | 0.037TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |